Wuxi Unigroup Microelectronics Co.,Ltd.

60V N-Channel DTMOS

Features

- Trench Power DTMOS Technology
- Low $R_{DS(ON)}$
- Low Gate Charge
- Optimized for Fast-switching Applications

Applications

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial

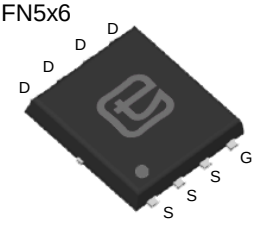
Product Summary

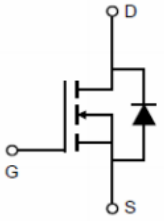
V_{DS}	60V
RDS(ON) (at VGS=10V)	< 9mΩ
RDS(ON) (at VGS=4.5V)	< 13.5mΩ
ID (at VGS=10V)	60A

100% UIS Tested

RoHS

DFN5x6





Device	Package	Marking
TSG12N06AT	DFN5×6	12N06AT

Absolute Maximum Ratings T_C = 25ºC, unless otherwise noted

Parameter		Symbol	Value	Unit
Drain-Source Voltage (V_{GS} = 0V)		V_{DSS}	60	V
Continuous Drain Current	T_C = 25ºC	I_D	60	A
	T_C = 100ºC		36	
Pulsed Drain Current (note1)		I_{DM}	240	A
Gate-Source Voltage		V_{GSS}	±20	V
Single Pulse Avalanche Energy (note2)		E_{AS}	65	mJ
Avalanche Current (note1)		I_{As}	36	A
Power Dissipation (T_C = 25ºC)		P_D	56.5	W
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55~+175	ºC

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	1.7	ºC/W
Thermal Resistance, Junction-to-Ambient	R_{thJA}	50	

Specifications T_J = 25ºC, unless otherwise noted

Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 250μA	60	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 60V, V_{GS} = 0V, T_J = 25ºC	--	--	1	μA
		V_{DS} = 60V, V_{GS} = 0V, T_J = 100ºC	--	--	100	
Gate-Source Leakage	I_{GSS}	V_{GS} = ±20V	--	--	±100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250μA	1.1	--	2.5	V
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	V_{GS} = 10V, I_D = 20A	--	6.5	9	mΩ
		V_{GS} = 4.5V, I_D = 20A	--	10.7	13.5	
Forward Transconductance (Note3)	g_{fs}	V_{DS} = 5V, I_D = 20A	--	85	--	S
Dynamic						
Input Capacitance	C_{iss}	V_{GS} = 0V, V_{DS} = 30V, f = 1.0MHz	--	2455	--	pF
Output Capacitance	C_{oss}		--	240	--	
Reverse Transfer Capacitance	C_{rss}		--	34	--	
Total Gate Charge	Q_g(10V)	V_{DD} = 30V, I_D = 20A, V_{GS} = 10V	--	45	--	nC
	Q_g(4.5V)		--	24	--	
Gate-Source Charge	Q_{gs}		--	6.8	--	
Gate-Drain Charge	Q_{gd}		--	11.5	--	
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 30V, I_D = 20A, R_G = 3Ω	--	8	--	ns
Turn-on Rise Time	t_r		--	3	--	
Turn-off Delay Time	$t_{d(off)}$		--	25	--	
Turn-off Fall Time	t_f		--	4	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	T_C = 25ºC	--	--	46	A
Pulsed Diode Forward Current	I_{SM}		--	--	138	
Body Diode Voltage	V_{SD}	T_J = 25ºC, I_{SD} = 1A, V_{GS} = 0V	--	0.72	1	V
Reverse Recovery Time	t_{rr}	I_F = 20A, di_F/dt = 500A/μs	--	25	--	ns
Reverse Recovery Charge	Q_{rr}		--	110	--	nC

Notes

1. Repetitive Rating: Pulse Width limited by maximum junction temperature
2. I_{AS} = 36A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 1%

Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 1. Output Characteristics

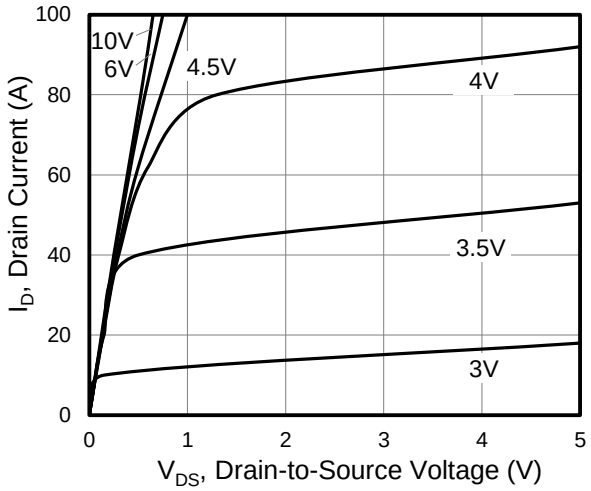


Figure 2. Transfer Characteristics

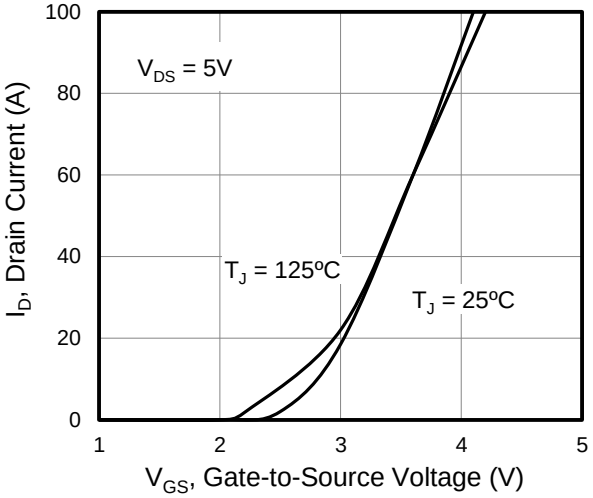


Figure 3. On-Resistance vs. Drain Current

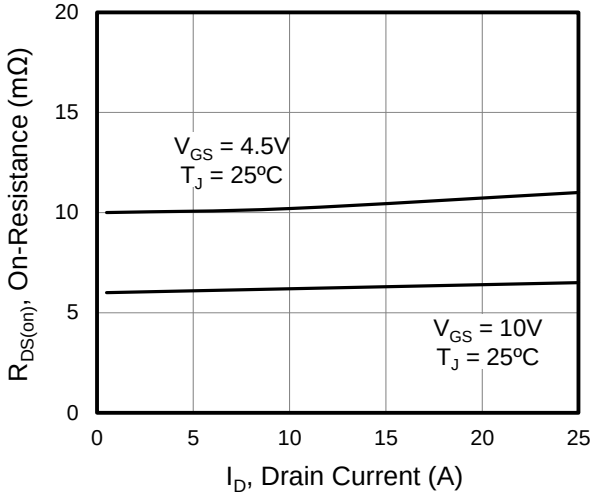


Figure 4. Capacitance

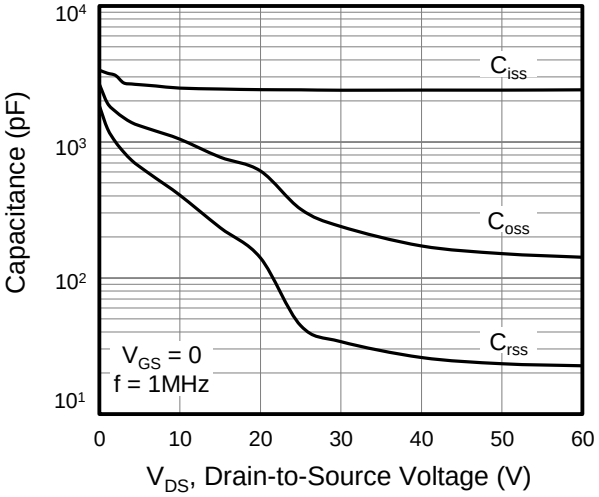


Figure 5. Gate Charge

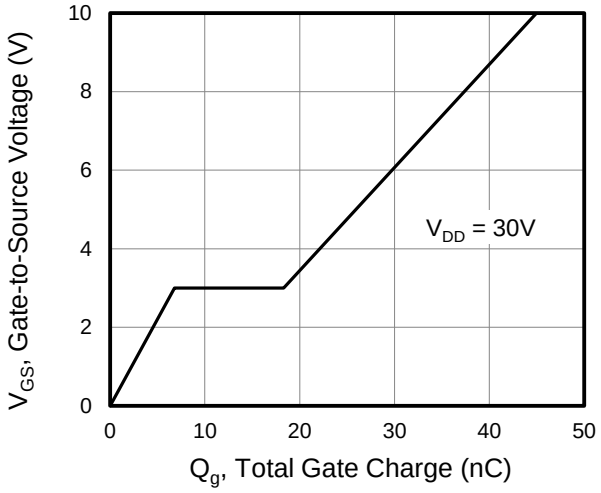
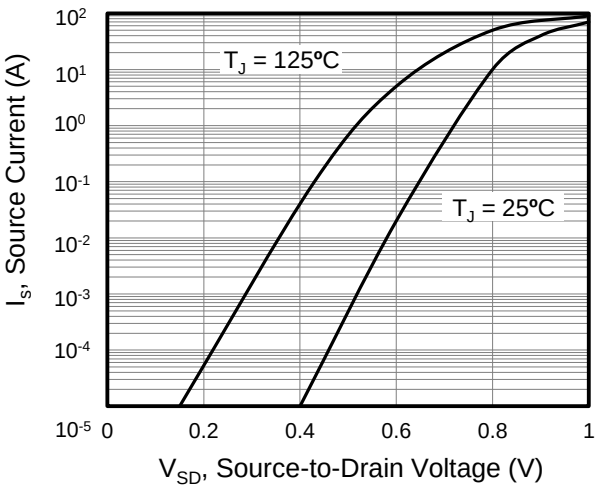


Figure 6. Body Diode Forward Voltage



Typical Characteristics T_J = 25ºC, unless otherwise noted

Figure 7. On-Resistance vs. Junction Temperature

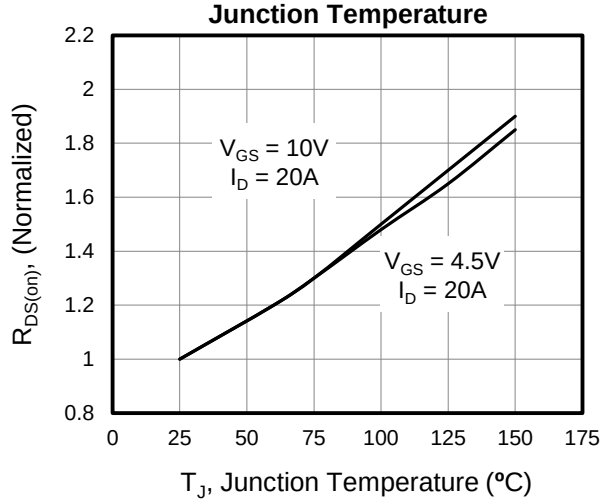


Figure 8. Threshold Voltage vs. Junction Temperature

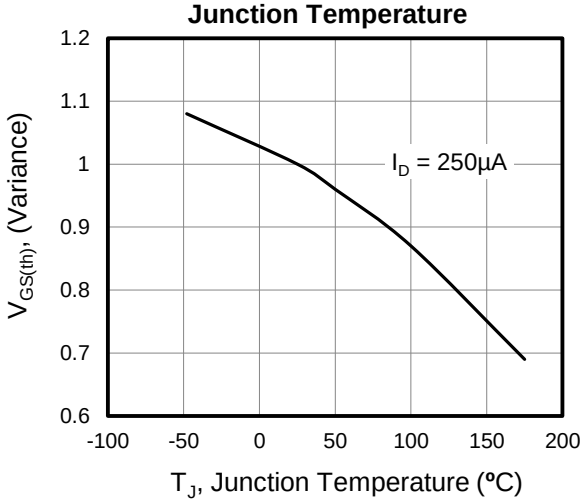


Figure 9. Transient Thermal Impedance

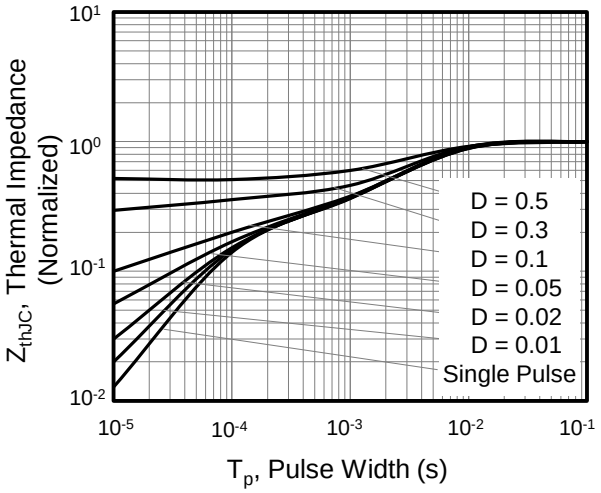


Figure 10. Safe operation area

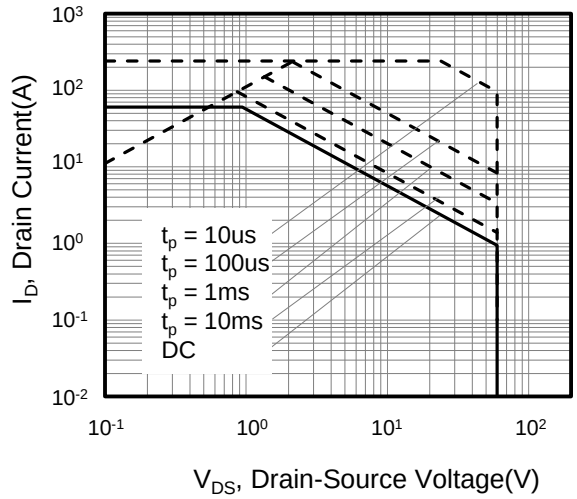


Figure A：Gate Charge Test Circuit and Waveform

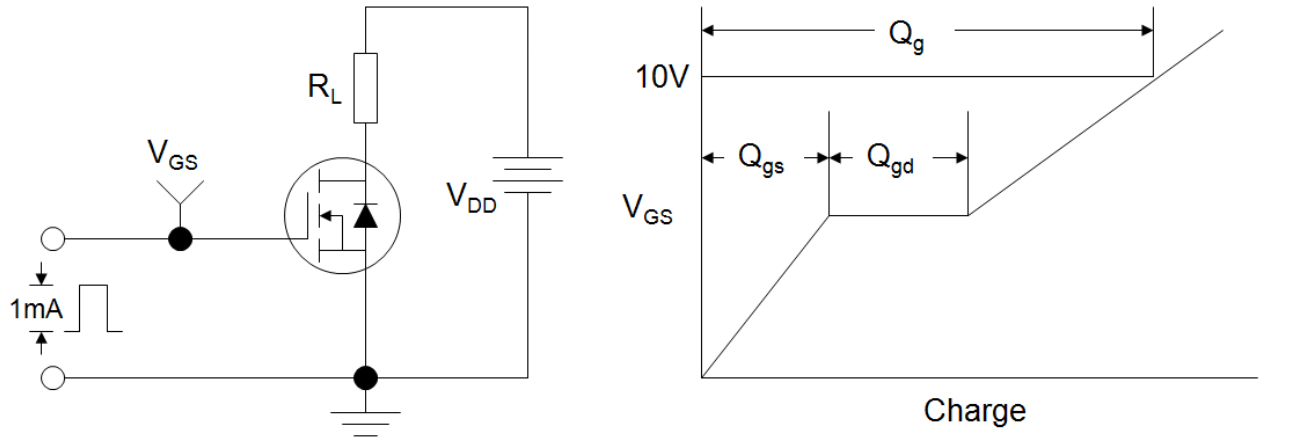


Figure B：Resistive Switching Test Circuit and Waveform

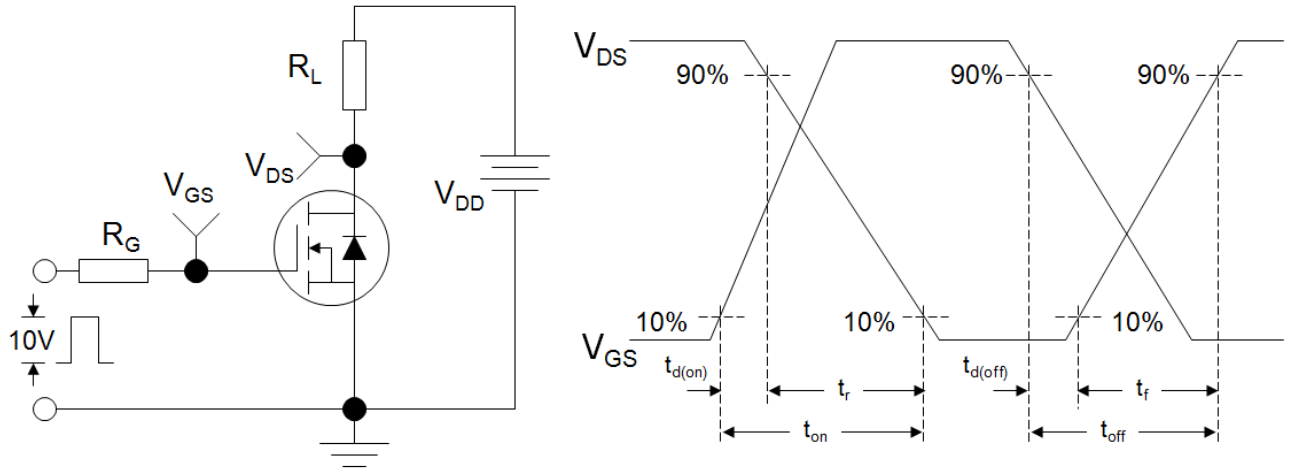
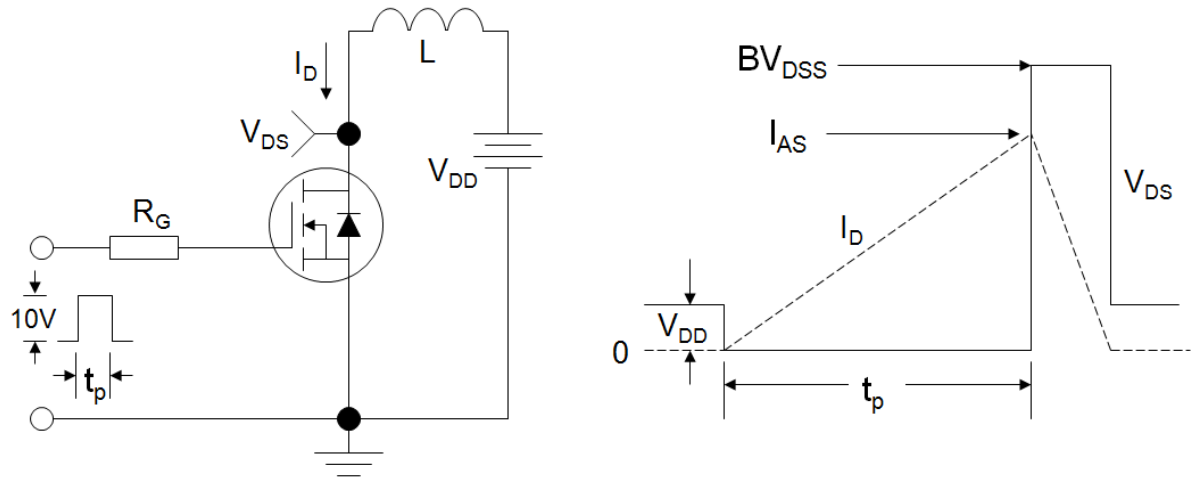
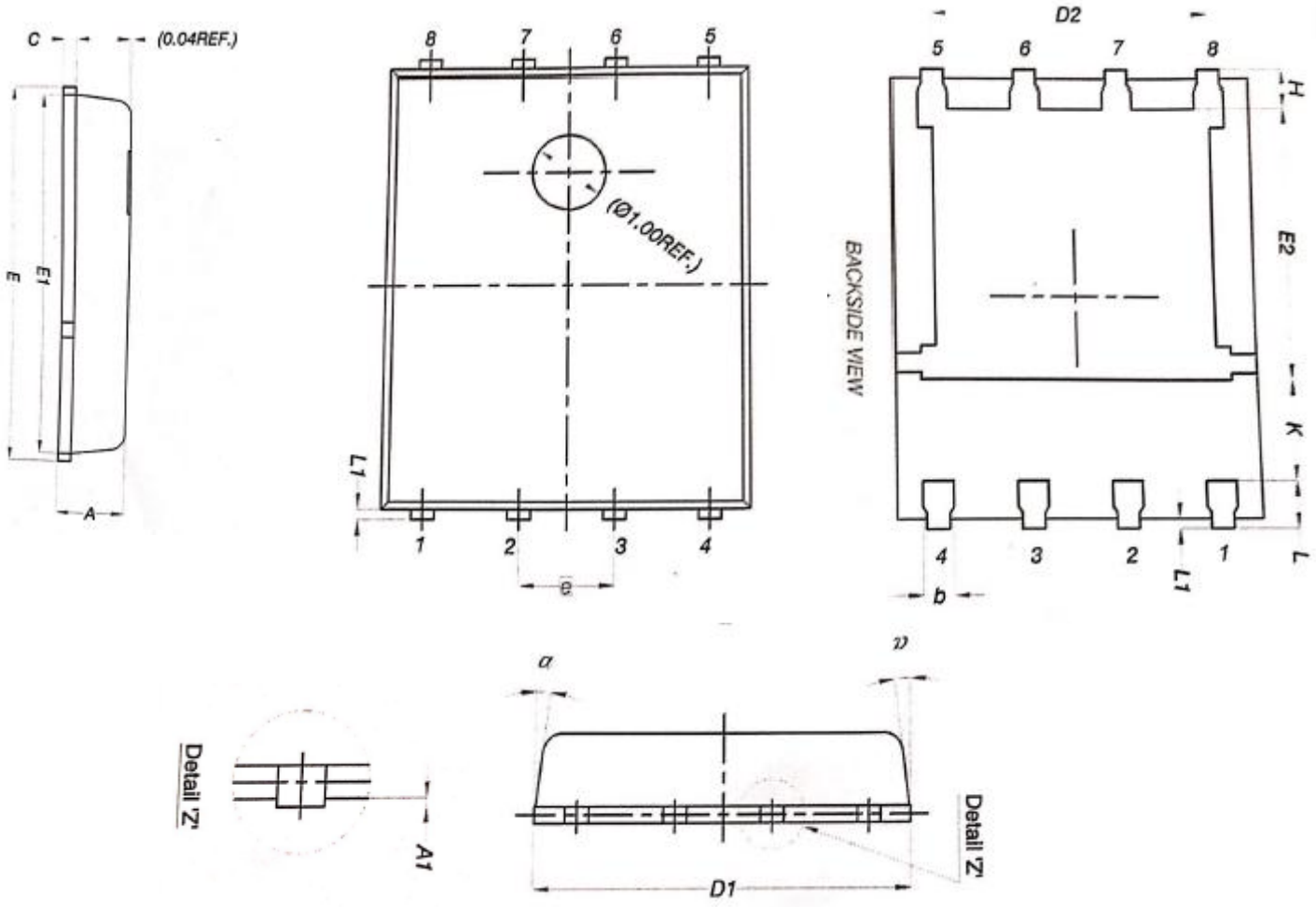


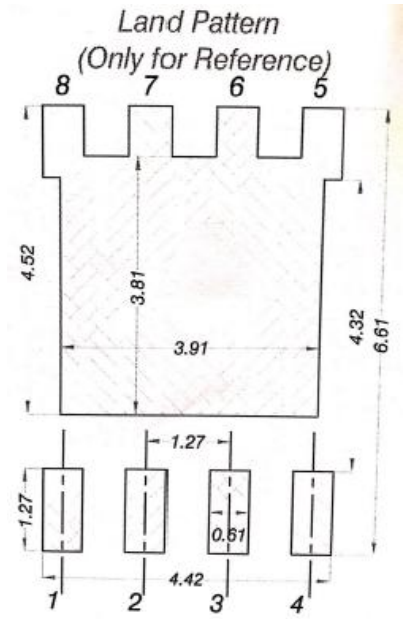
Figure C：Unclamped Inductive Switching Test Circuit and Waveform



DFN5×6 PACKAGR OUTLINE



DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0	-	0.05
b	0.33	0.41	0.51
C	0.20	0.25	0.30
D1	4.80	4.90	5.00
D2	3.61	3.81	3.96
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
e	1.27 BSC		
H	0.41	0.51	0.61
K	1.10	-	-
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
α	0°	-	12°



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